# **Dual Non-Inverting Buffer**

The NLU2G16 MiniGate<sup>™</sup> is an advanced high-speed CMOS dual non-inverting buffer in ultra-small footprint.

The NLU2G16 input and output structures provide protection when voltages up to 7.0 V are applied, regardless of the supply voltage.

#### **Features**

- High Speed:  $t_{PD} = 3.5 \text{ ns (Typ)} @ V_{CC} = 5.0 \text{ V}$
- Low Power Dissipation:  $I_{CC} = 1 \mu A \text{ (Max)}$  at  $T_A = 25 \text{°C}$
- Power Down Protection Provided on inputs
- Balanced Propagation Delays
- Overvoltage Tolerant (OVT) Input and Output Pins
- Ultra-Small Packages
- These are Pb-Free Devices

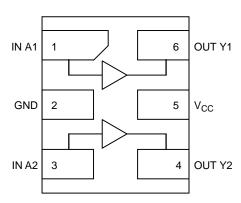


Figure 1. Pinout (Top View)

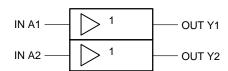


Figure 2. Logic Symbol

#### **PIN ASSIGNMENT**

| 1 | IN A1           |  |  |  |
|---|-----------------|--|--|--|
| 2 | GND             |  |  |  |
| 3 | IN A2           |  |  |  |
| 4 | OUT Y2          |  |  |  |
| 5 | V <sub>CC</sub> |  |  |  |
| 6 | OUT Y1          |  |  |  |

# **FUNCTION TABLE**

| Α | Y |
|---|---|
| L | L |
| H | H |



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# MARKING DIAGRAMS



UDFN6 1.0 x 1.0 CASE 517BX





UDFN6 1.2 x 1.0 CASE 517AA





UDFN6 1.45 x 1.0 CASE 517AQ



C, 4, R, E = Device Marking M = Date Code

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

#### **MAXIMUM RATINGS**

| Symbol               | Parameter   |                       | Value        | Unit |  |
|----------------------|---|-----------------------|--------------|------|--|
| V <sub>CC</sub>      | DC Supply Voltage                                       | DC Supply Voltage     |              |      |  |
| V <sub>IN</sub>      | DC Input Voltage  | DC Input Voltage      |              |      |  |
| V <sub>OUT</sub>     | DC Output Voltage                                       |                       | -0.5 to +7.0 | V    |  |
| I <sub>IK</sub>      | DC Input Diode Current                                  | V <sub>IN</sub> < GND | -20          | mA   |  |
| l <sub>ok</sub>      | DC Output Diode Current                                 | ±20                   | mA           |      |  |
| I <sub>O</sub>       | DC Output Source/Sink Current                           | ±12.5                 | mA           |      |  |
| I <sub>CC</sub>      | DC Supply Current Per Supply Pin                        | ±25                   | mA           |      |  |
| I <sub>GND</sub>     | DC Ground Current per Ground Pin                        |                       | ±25          | mA   |  |
| T <sub>STG</sub>     | Storage Temperature Range                               |                       | -65 to +150  | °C   |  |
| TL                   | Lead Temperature, 1 mm from Case for 10 Secon           | nds                   | 260          | °C   |  |
| TJ                   | Junction Temperature Under Bias                         | 150                   | °C           |      |  |
| MSL                  | Moisture Sensitivity                                    | Level 1               |              |      |  |
| F <sub>R</sub>       | Flammability Rating Oxygen                              | UL 94 V-0 @ 0.125 in  |              |      |  |
| I <sub>LATCHUP</sub> | Latchup Performance Above V <sub>CC</sub> and Below GNI | D at 125°C (Note 2)   | ±500         | mA   |  |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow.

# **RECOMMENDED OPERATING CONDITIONS**

| Symbol           | Parameter  | Min    | Max       | Unit |
|------------------|--|--------|-----------|------|
| V <sub>CC</sub>  | Positive DC Supply Voltage   | 1.65   | 5.5       | V    |
| V <sub>IN</sub>  | Digital Input Voltage  | 0      | 5.5       | V    |
| V <sub>OUT</sub> | Output Voltage   | 0      | 5.5       | V    |
| T <sub>A</sub>   | Operating Free–Air Temperature   |        | +125      | °C   |
| Δt/ΔV            | Input Transition Rise or Fall Rate $ \begin{array}{c} V_{CC} = 3.3 \ V \pm 0.3 \ V \\ V_{CC} = 5.0 \ V \pm 0.5 \ V \end{array} $ | 0<br>0 | 100<br>20 | ns/V |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

<sup>2.</sup> Tested to EIA / JESD78.

# DC ELECTRICAL CHARACTERISTICS

|                 |                              |  | V <sub>CC</sub>   | T,                        | <sub>A</sub> = 25 ° | С                         | T <sub>A</sub> = -        | +85°C                     |                   | 55°C to<br>5°C            |      |
|-----------------|------------------------------|--|-------------------|---------------------------|---------------------|---------------------------|---------------------------|---------------------------|-------------------|---------------------------|------|
| Symbol          | Parameter                    | Conditions   | (V)               | Min                       | Тур                 | Max                       | Min                       | Max                       | Min               | Max                       | Unit |
| V <sub>IH</sub> | Low-Level<br>Input Voltage   |  | 1.65              | 0.75 x<br>V <sub>CC</sub> |                     |                           | 0.75 x<br>V <sub>CC</sub> |                           |                   |                           | V    |
|                 |                              |  | 2.3 to<br>5.5     | 0.70 x<br>V <sub>CC</sub> |                     |                           | 0.70 x<br>V <sub>CC</sub> |                           |                   |                           |      |
| $V_{IL}$        | Low-Level<br>Input Voltage   |  | 1.65              |                           |                     | 0.25 x<br>V <sub>CC</sub> |                           | 0.25 x<br>V <sub>CC</sub> |                   | 0.25 x<br>V <sub>CC</sub> | V    |
|                 |                              |  | 2.3 to<br>5.5     |                           |                     | 0.30 x<br>V <sub>CC</sub> |                           | 0.30 x<br>V <sub>CC</sub> |                   | 0.30 x<br>V <sub>CC</sub> |      |
| V <sub>OH</sub> | High-Level<br>Output Voltage | $V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -50  \mu\text{A}$                       | 2.0<br>3.0<br>4.5 | 1.9<br>2.9<br>4.4         | 2.0<br>3.0<br>4.5   |                           | 1.9<br>2.9<br>4.4         |                           | 1.9<br>2.9<br>4.4 |                           | V    |
|                 |                              | $V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -4 \text{ mA}$ $I_{OH} = -8 \text{ mA}$ | 3.0<br>4.5        | 2.58<br>3.94              |                     |                           | 2.48<br>3.80              |                           | 2.34<br>3.66      |                           | V    |
| V <sub>OL</sub> | Low-Level<br>Output Voltage  | $V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 50  \mu\text{A}$                        | 2.0<br>3.0<br>4.5 |                           | 0<br>0<br>0         | 0.1<br>0.1<br>0.1         |                           | 0.1<br>0.1<br>0.1         |                   | 0.1<br>0.1<br>0.1         | V    |
|                 |                              | $V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 4 \text{ mA}$ $I_{OL} = 8 \text{ mA}$   | 3.0<br>4.5        |                           |                     | 0.36<br>0.36              |                           | 0.44<br>0.44              |                   | 0.52<br>0.52              |      |
| I <sub>IN</sub> | Input Leakage<br>Current     | $0 \le V_{IN} \le 5.5 V$   | 0 to<br>5.5       |                           |                     | ±0.1                      |                           | ±1.0                      |                   | ±1.0                      | μΑ   |
| Icc             | Quiescent<br>Supply Current  | V <sub>IN</sub> = 5.5 V or<br>GND  | 5.5               |                           |                     | 1.0                       |                           | 10                        |                   | 40                        | μΑ   |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

# AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ nS}$ )

|                    |  | V <sub>CC</sub> | Test                   | Т   | <sub>A</sub> = 25 ° | С    | T <sub>A</sub> = + | -85°C | T <sub>A</sub> = -5<br>+12 |      |      |
|--------------------|--|-----------------|------------------------|-----|---------------------|------|--------------------|-------|----------------------------|------|------|
| Symbol             | Parameter                                    | (V)             | Condition              | Min | Тур                 | Max  | Min                | Max   | Min                        | Max  | Unit |
| t <sub>PLH</sub> , | Propagation Delay,                           | 3.0 to          | C <sub>L</sub> = 15 pF |     | 4.5                 | 7.1  |                    | 8.5   |                            | 10   | ns   |
| tPHL               | Input A to Output Y                          | 3.6             | C <sub>L</sub> = 50 pF |     | 6.4                 | 10.6 |                    | 12    |                            | 14.5 |      |
|                    |  | 4.5 to          | C <sub>L</sub> = 15 pF |     | 3.5                 | 5.5  |                    | 6.5   |                            | 8.0  |      |
|                    |  | 5.5             | C <sub>L</sub> = 50 pF |     | 4.5                 | 7.5  |                    | 8.5   |                            | 10   |      |
| C <sub>IN</sub>    | Input Capacitance                            |                 |                        |     | 4.0                 | 10   |                    | 10    |                            | 10   | pF   |
| C <sub>PD</sub>    | Power Dissipation<br>Capacitance<br>(Note 3) | 5.0             |                        |     | 8.0                 |      |                    |       |                            |      | pF   |

<sup>3.</sup> C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the dynamic operating current consumption without load. Average operating current can be obtained by the equation I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no–load dynamic power consumption: P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.

# **SWITCHING WAVEFORMS**

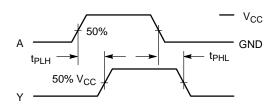
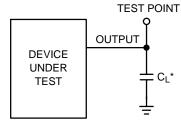


Figure 3. Switching Waveforms



\*Includes all probe and jig capacitance

Figure 4. Test Circuit

# **ORDERING INFORMATION**

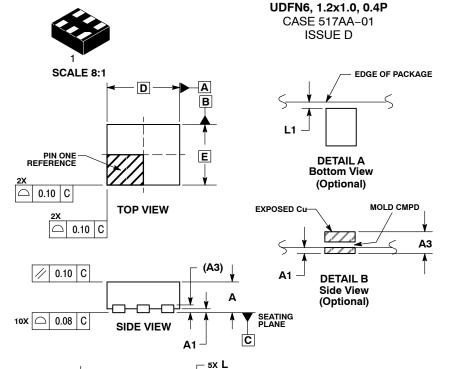
| Device        | Device Package                       |                    |
|---------------|--------------------------------------|--------------------|
| NLU2G16MUTCG  | UDFN6, 1.2 x 1.0, 0.4P<br>(Pb-Free)  | 3000 / Tape & Reel |
| NLU2G16AMUTCG | UDFN6, 1.45 x 1.0, 0.5P<br>(Pb–Free) | 3000 / Tape & Reel |
| NLU2G16CMUTCG | UDFN6, 1.0 x 1.0, 0.35P<br>(Pb–Free) | 3000 / Tape & Reel |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

6X b

0.10 С A B

0.05 С NOTE 3



е

**BOTTOM VIEW** 

**DATE 03 SEP 2010** 

#### NOTES

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 mm FROM TERMINAL.

  COPLANARITY APPLIES TO THE EXPOSED
- PAD AS WELL AS THE TERMINALS.

|     | MILLIMETERS |      |  |  |  |
|-----|-------------|------|--|--|--|
| DIM | MIN MAX     |      |  |  |  |
| Α   | 0.45        | 0.55 |  |  |  |
| A1  | 0.00        | 0.05 |  |  |  |
| А3  | 0.127       | REF  |  |  |  |
| b   | 0.15        | 0.25 |  |  |  |
| D   | 1.20        | BSC  |  |  |  |
| Е   | 1.00        | BSC  |  |  |  |
| е   | 0.40 BSC    |      |  |  |  |
| Ĺ   | 0.30        | 0.40 |  |  |  |
| L1  | 0.00        | 0.15 |  |  |  |
| 12  | 0.40        | 0.50 |  |  |  |

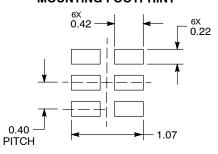
#### **GENERIC** MARKING DIAGRAM\*



= Specific Device Code = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

# **MOUNTING FOOTPRINT\***



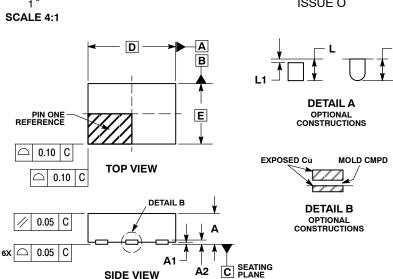
DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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6X L

6X b

0.10 | C | A | B

0.05 C NOTE 3

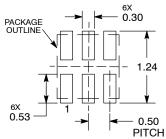
#### UDFN6, 1.45x1.0, 0.5P CASE 517AQ **ISSUE O**

**DATE 15 MAY 2008** 

- NOTES:
  1. DIMENSIONING AND TOLERANCING PER
- ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM THE TERMINAL TIP.

|     | MILLIMETERS |      |  |  |  |  |
|-----|-------------|------|--|--|--|--|
| DIM | MIN MAX     |      |  |  |  |  |
| Α   | 0.45        | 0.55 |  |  |  |  |
| A1  | 0.00        | 0.05 |  |  |  |  |
| A2  | 0.07 REF    |      |  |  |  |  |
| b   | 0.20        | 0.30 |  |  |  |  |
| D   | 1.45 BSC    |      |  |  |  |  |
| Е   | 1.00 BSC    |      |  |  |  |  |
| Ф   | 0.50 BSC    |      |  |  |  |  |
| L   | 0.30        | 0.40 |  |  |  |  |
| L1  |             | 0.15 |  |  |  |  |

#### **MOUNTING FOOTPRINT**



**DIMENSIONS: MILLIMETERS** 

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# **GENERIC MARKING DIAGRAM\***

**BOTTOM VIEW** 



= Specific Device Code

= Date Code

е

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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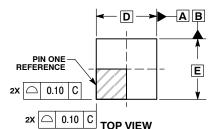
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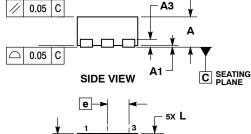


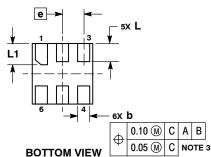


UDFN6, 1x1, 0.35P CASE 517BX **ISSUE O** 

**DATE 18 MAY 2011** 





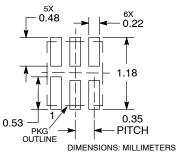


#### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN
- 0.15 AND 0.20 MM FROM TERMINAL TIP. PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

|     | MILLIMETERS |      |  |  |  |
|-----|-------------|------|--|--|--|
| DIM | MIN         | MAX  |  |  |  |
| Α   | 0.45        | 0.55 |  |  |  |
| A1  | 0.00        | 0.05 |  |  |  |
| A3  | 0.13 REF    |      |  |  |  |
| b   | 0.12        | 0.22 |  |  |  |
| D   | 1.00        | BSC  |  |  |  |
| E   | 1.00        | BSC  |  |  |  |
| е   | 0.35 BSC    |      |  |  |  |
| L   | 0.25        | 0.35 |  |  |  |
| L1  | 0.30        | 0.40 |  |  |  |

#### **RECOMMENDED SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# **GENERIC MARKING DIAGRAM\***



X = Specific Device Code

M = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

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